



DP/HDMI 1:3 De-multiplexer switches

Features

- → DP/HDMI 1:3 De-multiplexer switch with 4 high speed differential channel and AUX/DDC, HPD and CAB_DET signal channels
- → Two passive output ports for DP1.2 at5.4Gbps signals
- → One active output port with integrated DP to HDMI redriver (level shifter) supports HDMI 1.4 at 3.4Gbps
- → Pin control mode supports auto port priority selection
- → Pin control mode supports port3 with DDC bi-direction buffer switch only
- → I2C control mode supports auto port priority selection
- → I2C control mode supports port3 with 8 levels equalization and 5 levels pre-emphasis
- → I2C control mode supports port3 with either DDC bidirection buffer switch or DDC passive switch
- → Very low operating power when passive port1 and port2 are selected
- → 3.3V power supply
- → 2KV HBM ESD protection for all I/O pins
- → Support Type2 cable ID register
- → Packaging:

60 pin TQFN package (5x9mm, 0.4mm pitch)

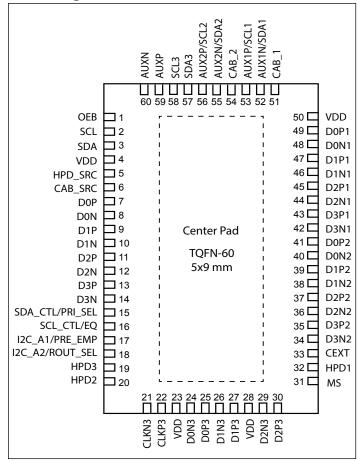
Description

PI3WVR31313A has two passive output port1 and port2, one active (DP to HDMI) output port3. Passive output ports support DP1.2 at 5.4Gbps. Active port3 support HDMI1.4b at 3.4Gbps. All three output ports support auto port priority selection. Input port accepts DP1.2 and DP++ signals associated with output ports as described above.

Application

→ Notebook

Pin Configuration: TQFN-60

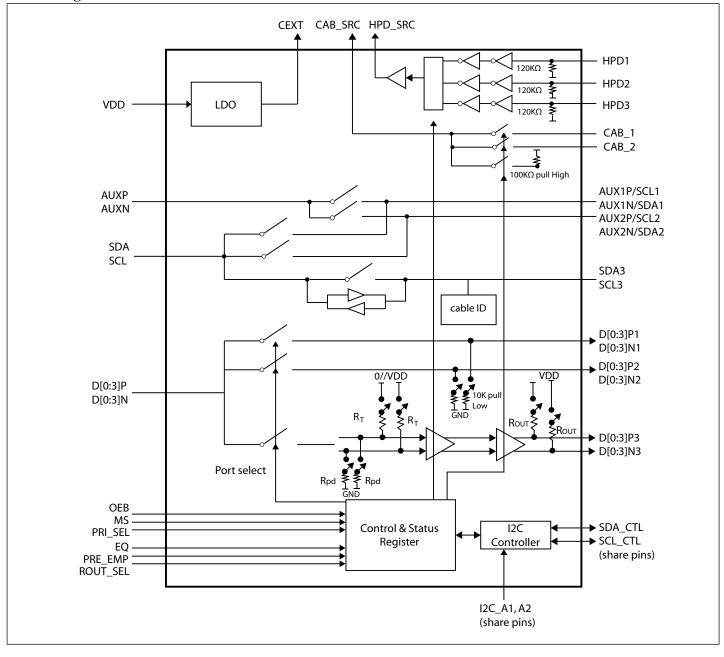


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Block Diagram



17-0053

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Pin Description

pin#	pin Name	Signal Type	Description
7	D0P		
9	D1P		
11	D2P		
13	D3P	т	4 differential pair input (DD or DD))
8	D0N	1	
10	D1N		
12	D2N		
14	D3N		
49	D0P1		
47	D1P1		
45	D2P1		
43	D3P1		
48	D0N1		
46	D1N1		
44	D2N1		
42	D3N1	0	4 differential pair output (DP) for part 1 and part 2
41	D0P2	I 4 differential pair input (DP or DP++)	4 unierential part output (DF) for port 1 and port 2
39	D1P2		
37	D2P2	I 4 differential pair input (DP or DP++) O 4 differential pair output (DP) for port 1 and port 2	
35	D3P2		
40	D0N2		
38	D1N2		
36	D2N2		
34	D3N2		
30	D2P3		
27	D1P3		
25	D0P3		
29	D2N3		4 differential pair output (HDMI) for part 3
26	D1N3		+ uniciential pair output (112/01) 101 port 5
24	D0N3		
22	CLKP3		
21	CLKN3		





pin#	pin Name	Signal Type	Description				
52	AUX1N/SDA1						
55	•						
52 55 53 56 57 58 60 59 32 20 19 5 51 54 6 1 15 16 17 18 31 33 4, 23, 28, 50	AUX1P/SCL1	IO	AUX (DP) or DDC (HDMI) to three ports				
56	AUX2P/SCL2	10	ACA (DP) of DDC (HDMI) to three ports				
57	SDA3						
58	SCL3						
60	AUXN	ю					
59	AUXP	IO	AUX to DP-source				
3	SDA	10					
2	SCL	IO	DDC to DP-source				
32	HPD1	I					
20	HPD2	Ι	HPD1-3 for port1-3;				
19	HPD3	I	HPD_SRC to DP-source				
5	HPD_SRC	О					
			CAB_1: CAB_DET to port1				
			CAD_2: CAB_DET to port2				
		IO	CAB_SRC: CAB_DET to DP-source				
6	CAB_SRC		No CAB_DET for HDMI port3				
1	OEB	I	OEB=0, device active; OEB=1, device shut down				
1.5		Ŧ	MS=0, PRI_SEL selects priority in pin control mode;				
15	SDA_CTL/PRI_SE	I	MS=1, SDA_CTL as SDA in I2C control mode				
			MS=0, EQ selects equalization in pin control mode;				
16	SCL_CTL/EQ	IO	MS=1, SCL_CTL as SCL in I2C control mode				
		-	MS=0, PRE_EMP selects Pre-emphasis in pin control mode;				
17	12C_A1/PRE_EMP	I	MS=1, I2C_A1 as I2C address A1 in I2C control mode				
			MS=0, ROUT_SEL selects source termination in pin control				
18	I2C_A2/ROUT_SEL	I	mode;				
			MS=1, I2C_A2 as I2C address A2 in I2C control mode				
			Mode Select: MS pin with weak pull low resistor > 500Kohm				
31	MS	I	MS=0 or half VDD input level for pin control mode,				
			MS=1 for I2C control mode				
33	CEXT	0	Internal LDO bypass capacitance, 4.7uf to GND				
4, 23, 28, 50	VDD	Power	3.3V VDD				
Center Pad	GND	Ground	Bottom GND EPAD				





DP mode	HDMI/DVI mode	WVR31313A input pins	WVR31313A port1 output	WVR31313A port2 output	WVR31313A port3 output	
ML_lane0(P)	TX2+	D0P	D0P1	D0P2	D2P3	
ML_lane0(N)	TX2-	D0N	D0N1	D0N2	D2N3	
ML_lane1(P)	TX1+	D1P	D1P1	D1P2	D1P3	
ML_lane1(N)	TX1-	D1N	D1N1	D1N2	D1N3	
ML_lane2(P)	TX0+	D2P	D2P1	D2P2	D0P3	
ML_lane2(N)	TX0-	D2N	D2N1	D2N2	D0N3	
ML_lane3(P)	TXC+	D3P	D3P1	D3P2	CLKP3	
ML_lane3(N)	TXC-	D3N	D3N1	D3N2	CLKN3	

Pin mapping for dual mode DP source DEMUX to DP output

Function Description

The MS pin selects I2C or pin control mode.

Pin control mode has only automatic port selection. I2C control mode has automatic port selection.

In auto port selection, when only one HPD high detected, the port with HPD high will be selected. When multiple HPD high detected, the PRI_SEL pin(priority select) will determine the priority of the 3 ports.

When PRI_SEL=low, the port-priority will be port1-port2-port3 from high to low; when PRI_SEL=high, the port priority will be port1-port3-port2 from high to low; when PRI_SEL=M (open as not connected), the port priority will be port3-port1-port2 from high to low.

When port 1 (or port2) is selected and CAB_1 (or CAB_2) is low as in DP mode, the AUX/DDC channels will work as AUX channels. AUXP shall have 100Kohm external resistor to GND and AUXN shall have 100Kohm external resistor to VDD. The data rate of AUX channels will be >720Mbps.The internal DDC switch will be off.

When port 1 (or port2) is selected and CAB_1 (or CAB_2) is high when DP to HDMI adapter plugged, the AUX/DDC channels will work as DDC channels. The internal DDC channels are on and the AUX channels are off. The input of DDC channels can tolerate 5V input and voltage of DDC to source will be limited about 3.3V or below.

When port 1 or port 2 is selected (passive ports), port3 with HDMI re-driver will shut down.

When port 3 is selected, the internal DP to HDMI level shifter will be enabled. There will be 3 EQ and 3 Pre-emphasis settings in pin control mode, 8 EQ and 5 Pre-emphasis settings in I2C control mode.

When port 3 is selected, HDMI output can be standard TMDS-open-drain source, as well to be selected with internal source termination as 50 ohm pull up to 3.3V VDD, using ROUT_SEL pin control or I2C control.

When port 3 is active as DP to HDMP level shifter, the DDC channel can be selected between bi-direction DDC buffer and passive DDC switch.

HPD1, HPD2 and HPD3 are with internal CMOS buffers and can support 3.3V and 5V HPD inputs.

Squelch Mode

Squelch function will disable HDMI data output (as high impedance)when the voltage and frequency of input clock (TMDS) are below squelch threshold, which will prevent random noise presenting in HDMI data output, thereby prevent noise on sink display. Squelch function will enable-resume HDMI data output when input clock signals are above squelch threshold.





Truth Table for TMDS port3

EQ – three level pin control PRE-EMP - three level pin control

EQ	Equalization value
0	1.5dB
open	4.0dB
1	6.5dB

PRE_EMP	TX pre-emphasis
0	0dB
open	1.5dB
1	2.5dB

ROUT_SEL

ROUT_SEL	Pull-Up Resistors on port3 D[0:3]P3, D[0:3]N3
0	No Pull-up resistors
1	50Ω Pull-up resistors to VDD

MS – three level pin control

MS	Pin mode/type cable ID
0	Pin mode for Type 2 ID
M(0.5*vdd)	Pin mode for Type 1 ID
1	I2C mode

Priority Selection Table

PRI_SEL							
_ (Priority order)	HPD1	HPD2	HPD3	HPD_SRC	CAB_SRC	AUXP/AUXN	SDA/SCL
0	0	0	0	0	Hi-Z	Hi-Z	Hi-Z
0	1			LIDDI	CAB1=0	AUX1P/AUX1N	Hi-Z
0	1	x	X	HPD1	CAB1=1	Hi-Z	SDA1/SCL1
0	0	1		11002	CAB2=0	AUX2P/AUX2N	Hi-Z
0	0	1	X	HPD2	CAB2=1	Hi-Z	SDA2/SCL2
0	0	0	1	HPD3	High	Hi-Z	SDA3/SCL3
М	0	0	0	0	Hi-Z	Hi-Z	Hi-Z
М	1		0	LIDDI	CAB1=0	AUX1P/AUX1N	Hi-Z
М	1	x	0		CAB1=1	Hi-Z	SDA1/SCL1
M	0	1	0	LIDD2	CAB2=0	AUX2P/AUX2N	Hi-Z
М	0	1	0	HPD2	CAB2=1	Hi-Z	SDA2/SCL2
М	x	x	1	HPD3	High	Hi-Z	SDA3/SCL3
1	0	0	0	0	Hi-Z	Hi-Z	Hi-Z
1	1				CAB1=0	AUX1P/AUX1N	Hi-Z
1	1	x	X		CAB1=1	Hi-Z	SDA1/SCL1
1	0	1	0	LIDDO	CAB2=0	AUX2P/AUX2N	Hi-Z
1	0	1	U	0 0 0 HPD1 0 HPD2 1 HPD3 0 0 x HPD1 0 HPD2	CAB2=1	Hi-Z	SDA2/SCL2
1	0	x	1	HPD3	High	Hi-Z	SDA3/SCL3

Note: M=internal half VDD when input=HiZ





PRI_SEL											
(Priority order)	HPD1	HPD2	HPD3	D0P	D1P	D2P	D3P	DON	D1N	D2N	D3N
0	0	0	0	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
0	1	x	x	D0P1	D1P1	D2P1	D3P1	D0N1	D1N1	D2N1	D3N1
0	0	1	х	D0P2	D1P2	D2P2	D3P2	D0N2	D1N2	D2N2	D3N2
0	0	0	1	D2P3	D1P3	D0P3	CLKP3	D2N3	D1N3	D0N3	CLKN3
М	0	0	0	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
М	1	x	0	D0P1	D1P1	D2P1	D3P1	D0N1	D1N1	D2N1	D3N1
М	0	1	0	D0P2	D1P2	D2P2	D3P2	D0N2	D1N2	D2N2	D3N2
М	x	x	1	D2P3	D1P3	D0P3	CLKP3	D2N3	D1N3	D0N3	CLKN3
1	0	0	0	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
1	1	x	x	D0P1	D1P1	D2P1	D3P1	D0N1	D1N1	D2N1	D3N1
1	0	1	0	D0P2	D1P2	D2P2	D3P2	D0N2	D1N2	D2N2	D3N2
1	0	X	1	D2P3	D1P3	D0P3	CLKP3	D2N3	D1N3	D0N3	CLKN3

Note: M=internal half VDD when input=HiZ





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

	۱ı
Storage Temperature65°C to +150°C	
Storage Temperature65°C to +150°C Junction Temperature	
Supply Voltage to Ground Potential0.5V to +4.6V	0
High Speed Channel Input Voltage (DP Mode)0.5V to 2V DDC and HPD channels Input Voltage0.5V to 6V	i
DDC and HPD channels Input Voltage0.5V to 6V	
DC Output Current	[
Power Dissipation	

Note: Stresses greater than those listed under MAXI-MUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics

Recommended Operation Conditions

 $V_{DD} = 3.3V \pm 10\%$, Min and Max apply for T_A between -40°C to 85°C Typical values are referenced to T_A = 25°C

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Unit
V _{DD}	Operating Voltage		3.0	3.3	3.6	V
	VDD supply current (Port1 or 2 active)	VDD=3.3V		1	1.8	mA
I _{DD}	VDD Supply Current	Output Enable (open drain 500mv signal-end 0dB pre-emphasis, not including 40mA current to source)		80	100	mA
	(Port3 active)	Output Enable (double termination, 500mv signal-end 0dB pre-empha- sis, not including 40mA current to source)		160	200	mA
I _{DDQ}	VDD Quiescent Supply Current (port3 active w/o TMDS input)	TMDS Output Disable		3.5	5	mA
Isd1	Supply shut down current when OEB disable (MS=0)	V _{DD} =3.6V, OEB=high		0.1	0.2	mA
Isd2	Supply shut down current when OEB disable (MS=1)	V _{DD} =3.6V, OEB=high		0.6	1.2	mA





DC Electrical Characteristics for Switching over Operating Range

Parameter	Description	Test Conditions	Min.	Typ.	Max.	Unit
OEB, MS, ROU	T_SEL		l			
I _{IH}	High level digital input current	V _{IH} =VDD	-10		40	μA
I _{IL}	Low level digital input current	$V_{IL} = GND$	-10		10	μA
V _{IH}	High level digital input voltage		2.0			V
V _{IL}	Low level digital input voltage		0		0.8	V
HPD_SRC			l			
VOL_HPD_SRC	Buffer Output Low Voltage	$I_{OL} = 4 \text{ mA}$			0.4	V
V _{OH_HPD_SRC}	Buffer Output Low Voltage	$I_{OH} = 4 \text{ mA}$	2.4			V
HPD_sink						
I _{IH}	High level digital input current	V _{IH} =VDD	-10		40	μA
I _{IL}	Low level digital input current	$V_{IL} = GND$	-10		10	μΑ
V _{IH}	High level digital input voltage	V _{DD} =3.3V	2.0			V
V _{IL}	Low level digital input voltage		0		0.8	V
CAB			ł			1
I _{LK}	Input leakage current	Switch is off, Vin=5.5V	-50		50	uA
C _{IO}	Input/Output capacitance when- passive switch on			10		pF
R _{ON}	Passive Switch resistance	$I_{O} = 3mA, V_{O} = 0.4V$		25	50	Ω
V _{pass}	Switch Output voltage	V _I =3.3V, I _I =100uA	1.5	3.0	3.3	V
CI(source)	Source side CAB capacitance			3.5		pF
CI(sink)	Sink side CAB capacitance when	V_{I} peak-peak = 1V, 100 KHz		6.5		pF
SDA/SCL, SDA	1/SCL1, SDA2/SCL2		·			
I _{LK}	Input leakage current	DDC switch is off, Vin=5.5V	-50		50	uA
C _{IO}	Input/Output capacitance when passive switch on	V_{I} peak-peak = 1V, 100 KHz		8		pF
R _{ON}	Passive Switch resistance	$I_{O} = 3mA, V_{O} = 0.4V$		25	50	Ω
Vpass	Switch Output voltage	V _I =5.0V, I _I =100uA V _{DD} =3.3V	1.5	2.0	2.5	v
CI(source)	Source side DDC capacitance (passive switch off.)	V _I peak-peak = 1V, 100 KHz		2.5		pF
CI(sink)	Sink side DDC capacitance (pas- sive switch off.)	V_{I} peak-peak = 1V, 100 KHz		5		pF
SDA3/SCL3 (D	DC buffer of port3 active)					
V _{IH}	High level input voltage		2.0			V
V _{IL}	Low level input voltage	$V_{DD}=3.3V$	0		0.8	V
I _{LK}	Input leakage current	DDC switch is off, $Vin = 5.5V$	-10		10	uA

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Parameter	Description	Test Conditions	Min.	Typ.	Max.	Unit
I _{IL}	Low level input current	$V_{IL} = 0.2V$	-10		10	μΑ
V _{OL}	Low level output voltage	$I_{OL} = 4mA$			0.2	V
I _{LOH}	HIGH-level output leakage cur- rent	V _O =3.6V			10	μΑ
C _{IO}	Input/output capacitance	$V_{I} = 3 V \text{ or } 0 V; V_{CC} = 3.3 V \text{ or } 0V$		4		pF
SDA/SCL (DD	C buffer of port3 active)					
V _{IH}	High level input voltage		2.0			V
V _{IL}	Low level input voltage	$V_{DD}=3.3V$	0		0.4	V
I _{LK}	Input leakage current	DDC switch is off, Vin = 5.5V	-10		10	uA
I _{IL}	Low level input current	$V_{IL} = 0.2V$	-10		10	μA
V _{OL}	Low level output voltage	$I_{OL} = 4mA$	0.47	0.52	0.6	V
I _{LOH}	HIGH-level output leakage cur- rent	V _O =3.6V	5		10	μΑ
C _{IO} Input/output capacitance		$V_{I} = 3 V \text{ or } 0 V; V_{CC} = 3.3 V \text{ or } 0V$		8		pF
AUXP, AUXN,	, AUXnP/SCLn, AUXnN/SDAn	·				
I _{LK}	Input leakage current	DDC switch is off, Vin=5.5V	-50		50	uA
C _{IO}	Input/Output capacitance when passive switch on	V _I peak-peak = 1V, 100 KHz		6		pF
D		$I_{\rm O} = 3 {\rm mA}, V_{\rm O} = 0.3 {\rm V}$		5		Ω
R _{ON}	Passive Switch resistance	$I_{\rm O} = 3 {\rm mA}, V_{\rm O} = 3.0 {\rm V}$		10		Ω
V _{pass}	Switch Output voltage	V _I =5.5V, I _I =100uA V _{DD} =3.3V		4	4.5	V
CI(source)	Source side capacitance (passive switch off.)	V_{I} peak-peak = 1V, 100 KHz		2.5		pF
CI(sink)	Sink side capacitance (passive switch off.)	V_{I} peak-peak = 1V, 100 KHz		3.5		pF
High Speed Ch	annel (D[0:3]P/N – D[0:3]P1N1, D[0	:3]P/N – D[0:3]P2N2)				
V _{IK}	Clamp Diode Voltage (HS Chan- nel)	V_{DD} = Max., I_{IN} = -18mA		-1.6	-1.8	V
I _{IH}	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±10	1.
I _{IL}	Input LOW Current	V _{DD} = Max., V _{IN} = GND			±10	- μΑ
R _{ON_HS}	On resistance between input to out- put for high speed signals	V _{INPUT} ,cm = 0V to 1.2V, V _{INPUT} ,diff < 1.0Vp-p, diff, V _{DD} = 3.0V, I _{INPUT} = 20mA		8		Ohm





Parameter	Description	Test Conditions	Min.	Typ.	Max.	Unit
High Speed Cha						
VI(open) Single-ended input voltage under high impedance input or open input IL=10u		I _L =10uA	VDD-10		VDD+10	mV
R _T	Input termination resistance	V _{IN} =2.9V	45	50	66	ohm
I _{OZ}	Leakage current resistance	V _{DD} =3.6V, OEB=High		30	100	uA
Ioff	Power off leakage current	V _{DD} =0, V _{IN} =3.6V	-100		100	uA

Dynamic Electrical Characteristics over Operating Range

(T_A = -40° to +85°C, V_{DD} = 3.3V ±10%)

Parameter	Description Test Conditions		Min.	Тур.	Max.	Unit
TMDS Differe	ntial Pins			1	1	
t _{pd}	Propagation delay				2000	
t _r	Differential output signal rise time (20% - 80%)			120		
t _f	Differential output signal fall time (20% - 80%) $V_{DD} = 3.3V$, Rout = 50 Ω off, open drain, 0dB pre-emphasis			120		
t _{sk} (p)	Pulse skew			15	50	ps
t _{sk} (D)	Intra-pair differential skew	-		25	50	- P ⁰
t _{sk} (o)	Inter-pair differential skew(2)	_			100	
T _{jit_clk} (pp)	Peak-to-peak output jitter CLK residual jitter			15	40	
T _{jit_dat} (pp)	Peak-to-peak output jitter DATA Residual Jitter	short trace. CLK Input = 340 MHz clock		25	50	-
t _{en}	Enable time	when channel is active			10	
t _{dis}	Disable time				50	us
SCL, SDA char	nnel, AUX channel , CAB channel : pa	ssive switches				
t _{pd} (DDC)	Propagation delay from SCLn/ SDAn to SCL/SDA or SCL/SDA to SCLn/SDAn In passive SW on.	$C_{\rm L} = 10 {\rm pF}$, in passive switch			5	ns
SCL3, SDA3- S	SCL,SDA channel : buffers					
t _{PLH}	LOW-to-HIGH propagation delay	SCL/SDA to SCL3/SDA3	50	100	150	ns
t _{PHL}	HIGH-to-LOW propagation delay	SCL/SDA to SCL3/SDA3	10	20	40	ns
t _{PLH}	LOW-to-HIGH propagation delay	SCL3/SDA3 to SCL/SDA	50	100	150	ns
t _{PHL}	HIGH-to-LOW propagation delay	SCL3/SDA3 to SCL/SDA	10	20	40	ns





Parameter Description		Test Conditions	Min.	Тур.	Max.	Unit
Control and Stat	tus Pins (HPDn, HPD_SRC)					
tpd(HPD)	Propagation delay (from HPDx to the active port of HPD_SRC, high to low)			2	4	us
tsx(HPD)	Switch time (from port select to $CL = 10 \text{pF}$			2	4	us

Dynamic Electrical Characteristics

Parameter	Description	Test Conditions		Min.	Тур.	Max.	Unit			
High Speed Ch	High Speed Channel (D[0:3]P/N – D[0:3]P1N1, D[0:3]P/N - D[0:3]P2N2)									
X _{TALK}	Crosstalk on High Speed Channels	See Fig. 1 for Measurement	f= 2.7 GHz		-32	-30	-			
O _{IRR}	OFF Isolation on High Speed Channels	SetupSee Fig. 2 for MeasurementSetup			-19	-17	dB			
I _{LOSS}	Differential Insertion Loss on High Speed Channels	@2.7GHZ (see figure 3)		-1.7	-1.5		dB			
R _{loss}	Differential Return Loss on High Speed Channels	@ 2.7GHz (5.4Gbps)			-18	-16	dB			
BW_Dx±	Bandwidth -3dB for Main high speed path (Dx±)	See figure 3		5.1	5.6		GHz			
BW_AUX	Bandwidth -3dB for AUX	See figure 3		1.2	1.5		GHz			
Tstartup	V _{DD} valid to channel enable				250		us			
Twakeup	Enabling output by changing OEB from High to Low				250		us			
T _{pd}	Propagation delay (input pin to output pin) on all channels				80		ps			
t _{b-b}	Bit-to-bit skew within the same differential pair of Dx± channels				5	7	ps			
t _{ch-ch}	Channel-to-channel skew of Dx± channels					35	ps			





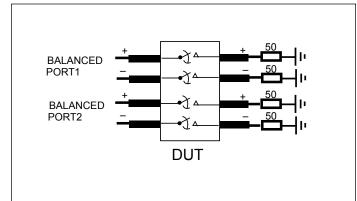


Fig 1. Crosstalk Setup

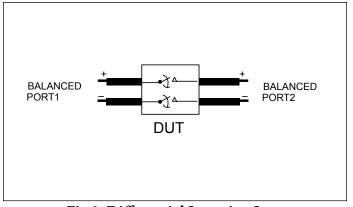


Fig 3. Differential Insertion Loss

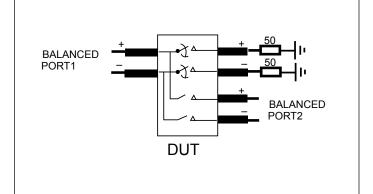


Fig 2. Off-isolation setup



A product Line of Diodes Incorporated

PI3WVR31313A

Differential Insertion Loss , Vdd=3.3V, 25C

File View Channel Sweep Calibration Trace Scale Marker System Window Help Marker: 1 of 3 Marker 1 2.7808211774 GHz 💠 Marker 1 Marker 2 Marker 3 Off 2.00 -051077 dB 2.000dB/ 0.00dB LogM 1.000000 MHz -0 51077 dB 0.00 5 56064 GH 5108 dB >4 2 78082 GHz 1.4467 dB 4 2.00 4.00 6.00 8.00 10.00 And the second and the second se 12.00 14.00 16.00 18.00 Stop 20.0000 GHz >Ch1: Start 1.00000 MHz -C 4-Port Hold CH 1: Sdd21 LCL

D0 to D01 Channel



D0 to D02 Channel



A product Line of Diodes Incorporated

PI3WVR31313A

Differential Return Loss , Vdd=3.3V, 25C

File View Channel Sweep Calibration Trace Scale Marker System Window Help Marker: 2 of 3 Marker 1 1.350000000 GHz 💠 Marker 4 Marker 5 Marker 6 Off 5.00 .075 dB 5.000dB/ 0.00dB LogM 2 2 78000 GHz 0.446 dE 0.00 GH 1238 dF 5.00 10.00 15.00 20.00 25.00 30.00 35.00 40.00 45.00 >Ch1: Start 1.00000 MHz -Stop 20.0000 GHz C 4-Port CH 1: Sdd11 LCL Hold

D0 to D01 Channel



D0 to D02 Channel



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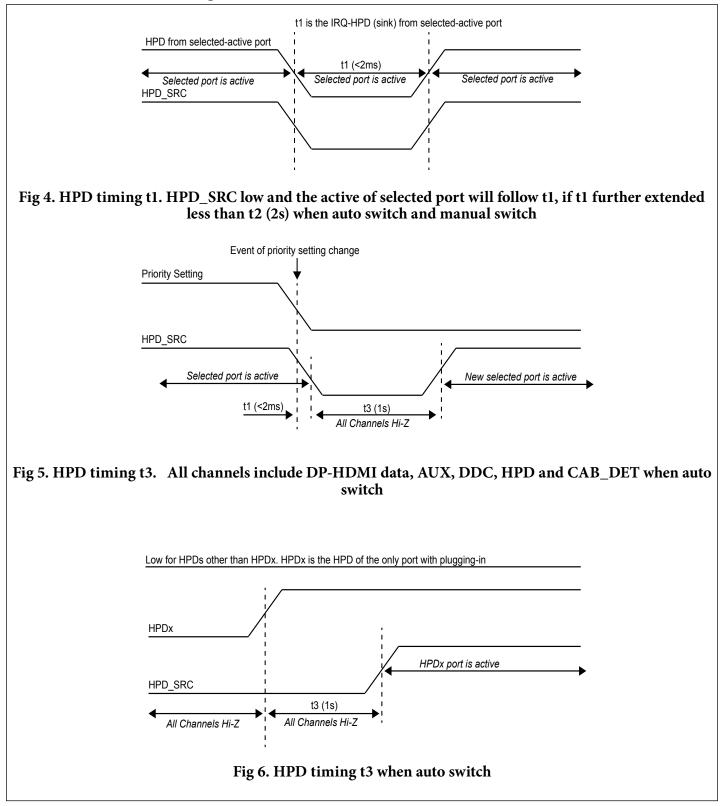
Differential Off Isolation , Vdd=3.3V, 25C

File View Channel Sweep Calibration Trace Scale Marker System Window Help Trigger Continuous Single Hold Restart 10.00 1.350000 GHz 2.700000 GHz 31.216 dB 22.534 dB dB Sdd2 >1 10.00dB/ 0.00dB LogM 2 0.00 8.526 dB 5,40000 GHz 10.00 20.00 3 1 2 30.00 40.00 50.00 60.00 70.00 80.00 90.00 Stop 20.0000 GHz >Ch1: Start 1.00000 MHz -Hold CH 1: Sdd21 C 4-Port LCL



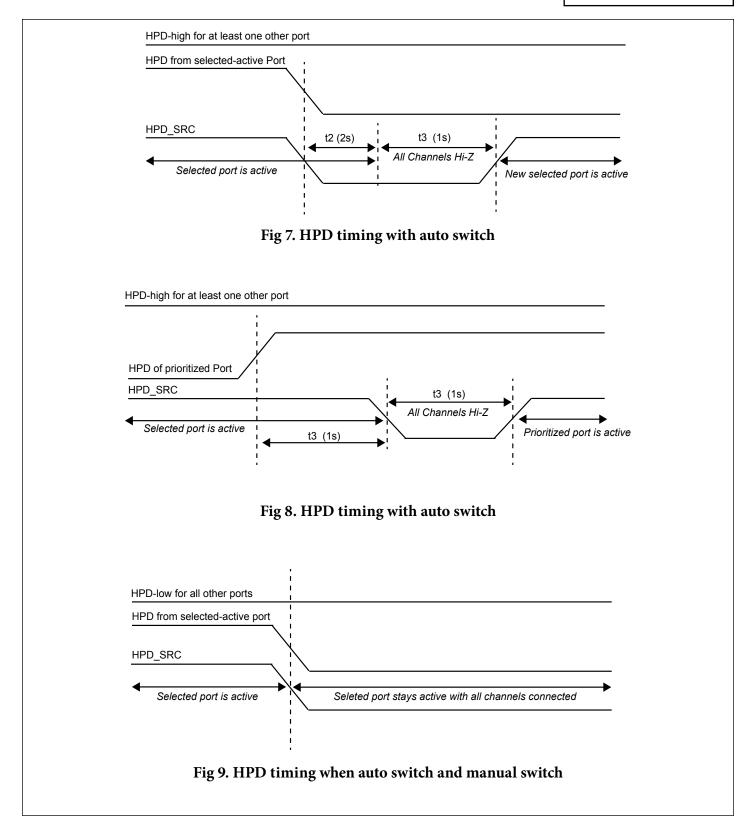


HPD auto selection timing waveform













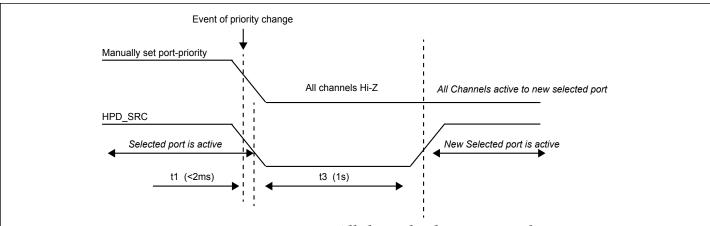


Fig 10. HPD timing t3. All channels when auto switch

Parameter	Test Conditions	Min.	Typ.*	Max.	Unit
HPD auto switching timing					
HPD pulse duration when treated as an IRQ -t1 (Figure 4)				2	ms
Propagation delay of HPDx Desertion -t2 (Figure 7)		1.0	2	3	s
HPD_SRC low duration when the outputs are switched -t3(Figure 5,6,7,8,10); Propagation delay of HPDx assertion (Figure 8)		0.5	1	1.5	S

*Typical time can be changed by I2C Byte 0x01 bit[2:0], and Byte 0x04 bit3.

I2C Address Byte

	b7(MSB)	b6	b5	b4	b3	b2	b1	b0 (R/W)
Address Byte	1	0	1	1	A2	A1	1	1/0*

* Read; 0:Write, A2 and A1 are two address bits setting

Data transmission format

Data is transmitted to the PI3WVR31313A registers using the Write mode as shown in Figure 1. Data is read from the PI3WVR31313A registers using the Read mode as shown in Figure 2.

Figure 1: I2C control register write condition

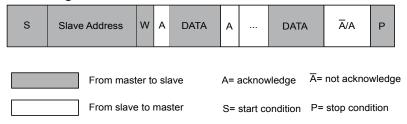


Figure 2: I2c control register read condition







I2C Control Register

The I2C control register uses index read or write for byte access.

Offset	Name	Description	Power Up Condition	Туре
Offset 0x00	Name CONFIG[7:0]	 [7] Reserved to 0 [6:5] Port SEL1/SEL0 selection control 00 port 1 (Reserved) 01 port 2 (Reserved) 10 port 3 (Reserved) 11 Auto selection mode depending on PRI_SEL below [4:2] PRI_SEL priority selection control by HPDx 000 port1/port2/port3 001 port1/port3/port2 010 port2/port1/port3 011 port2/port3/port1 1x0 port3/port1/port2 1x1 port3/port2/port1 [1] DP_HDMI selection control 	Power Up Condition 0x01	Type R/W
		0=DP input, 1=Reserved		
		 [0] Cable ID type selection 0=Type 2 cable ID 1=Type 1 cable ID 		





		[7:5] EQ programmable setting		
		000: 1.5 dB		
		001: 4 dB		
		010: 6.5 dB		
		011: 9 dB		
		100: 11.5 dB		
		101: 14 dB		
		110: 16.5 dB		
		111: 9 dB		
		[4:3] HPD auto selection time source control		
		00: normal		
	RX_SET[7:5]	01: -25%		
0x01	for port3; HPD auto selection	10: +25%	0x00	R/W
	time	11: test mode		
		[2] HPD auto selection time t3 setting		
		0: 256ms		
		1: 128ms		
		[1] HPD auto selection time t4 setting		
		0: 1024ms		
		1: 516ms		
		[0] HPD pulse duration treated as IRQ time t1 setting		
		0: 2ms		
		1: 4ms		





		Output setting for HDMI re-driver/level shifter		
		[7] HDMI output control		
		0: open drain		
		1: double termination		
		[6:4] HDMI output Pre-emphasis settings		
		000: 0dB		
		001: 1.5dB		
		010: 2.5dB		
		011: 3.5dB		
		100: 6dB		
0x02	TX_SET[7:0]	[3:2] TMDS output swing setting	0x00	R/W
	for port3	00: 500mv as default		
		01: -10%		
		10: +10%		
		11: +20%		
		[1] TMDS output slow rate setting		
		0: as default		
		1: +10%		
		[0] DP1 and DP2 port 10Kohm pull low control		
		0=10Kohm pull low on		
		1=10Kohm pull low off		
		Pericom Vendor Register ID (refer to PCIE clock buffer)		
0x03	Pericom ID	[7:4] Vendor ID 0101	0x51	R
		[3:0] device revision 0001		





0x04	HPDx/ CABx[6:0] Read only	 [7] HPD_SRC output logic function (buffer) 0: HPD_SRC=HPDx 1: HPD_SRC=/HPDx [6] DDC function for port 3 0: Active buffer 1: passive switch [5] Port switching in manual selection 1: disable T3 time pulse when port switching, Port switch immediately 0: Enable T3 time pulse when port switching [4] HPD auto selection time t2 setting 0: 128ms 1: 64ms [3] HPD3 status as read only [2] HPD2 status as read only 	0x00	R/W [7:4] R [3:0]
		[1] HPD1 status as read only[0] Reserved for HPD1B		

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Table of ID registers

Data address offset	Data as in spec	Read/White as in spec	Description as in spec	WVR31313A		
00h	44h	RO	D	D		
01h	50h	RO	Р	Р		
02h	2dh	RO	-	-		
03h	48h	RO	Н	Н		
04h	44h	RO	D	D		
05h	4dh	RO	М	М		
06h	49h	RO	Ι	Ι		
07h	20h	RO	Space	Space		
08h	41h	RO	А	А		
09h	44h	RO	D	D		
0ah	41h	RO	А	А		
0bh	50h	RO	Р	Р		
0ch	54h	RO	Т	Т		
0dh	4fh	RO	0	0		
0eh	52h	RO	R	R		
0fh	04h	RO		•		
10h	A0h	RO	Cable Adaptor Identifier	A0h		
11h	UD	RO	IEEE OUI 1st byte	00h		
12h	UD	RO	IEEE OUI 2nd byte	60h		
13h	UD	RO	IEEE OUI third byte	23h		
14h	UD	RO	Device Id	50h "P"		
15h	UD	RO	Device Id	49h "I"		
16h	UD	RO	Device Id	33h "3"		
17h	UD	RO	Device Id	57h "W"		
18h	UD	RO	Device Id	56h "V"		
19h	UD	RO	Device Id	52h "R"		
lah	UD	RO	Hardware (chip) revision 7:4h: major revision 3:0h: minor revision.	00h		
1bh	UD	RO	Firmware/software major revision	00h		
1ch	UD	RO	Firmware/software minor revision	00h		
1dh	UD	RO	Clock rate, specified max 300mhz for HDMI	78h: 300MHz (300/2.5=120=78h)		
1eh	0fh	RO	I2C speed control capabilities bit map	0fh		





1fh	00h	RW	Reserved data Address at 1fh: 1. DP source reads data address 1fh, ID register returns 00h 2. DP source writes data AAh to data address 1fh, ID register responds ACK or returns 00h.	1fh=00, RW, reserved			
20h	00h or 01h	R/W	TMDS output enable or disable. 00h: enabled 01h: disabled (<=10mV Voff)	00h, RW (Not Applicable for PI- 3WVR31313A) 00h: enabled			
			[7:1] Reserved Enables/disables the CEC Isolation Switch.	01h: disabled (<=10mV Voff) [7:1] Reserved 00h, RW (Not Applicable for PI-			
21h 0	00h or 01h	R/W	00h: enabled 01h: disabled [7:1] Reserved	3WVR31313A) 00h: enabled 01h: disabled [7:1] Reserved			
22h	UD	R/W	I2C speed control status bit map. 01h: 1Kbps 02h: 5Kbps 04h: 10Kbps 08h: 100Kbps 10h, 20h, 40h and 80h are reserved	08h for 100Khz. (Not Applicable for PI- 3WVR31313A) For the function specified as: 01h: 1Kbps 02h: 5Kbps 04h: 10Kbps 08h: 100Kbps 10h, 20h, 40h and 80h are reserved			
23h-ffh	00h	R/W	 Reserved data Address from 23h to ffh: 1. DP source reads data address 23h thru ffh, ID register returns 00h. 2. DP source writes data AAh to data address 23h thru ffh, ID register responds ACK or returns 00h. 	23h-ffh=00h, RW, reserved.			

Notes:

1. DP++ source accesses ID at device address 80h/81h with data offset from 00h-ffh.

2. UD: user dependent.

3. RO: read only.

4. OUI: IEEE Organizationally Unique Identifier.





ID Access Sequence Specified in DP Interoperability V1.1A

It is suggested that the Source-side cable adaptor have a voltage-level shifter to convert the 5-V HPD signal from a DVI/HDMI Sink Device to +2.25V ~ +3.6V voltage as specified the HPD signal input voltage range of DisplayPort Specification Ver.1.1a.

DDC Buffer ID of a Source-side HDMI Cable Adaptor

Offset	0	1	2	3	4	5	6	7	8	9	Ah	Bh	Ch	Dh	Eh	Fh
Data	44h	50h	2Dh	48h	44h	4Dh	49h	20h	41h	44h	41h	50h	54h	4Fh	52h	04h

Table below shows the I2C transaction sequence for a Source Device to read the DDC Buffer ID of the Source-side HDMI cable adaptor. I2C write for setting the address offset is optional for a Dual-mode Source Device. The HDMI cable adaptor must acknowledge it when it receives this write operation. The DVI cable adaptor must NACK the I2C transaction to Device Address 80h/81h.

DDC Buffer ID Access Sequence

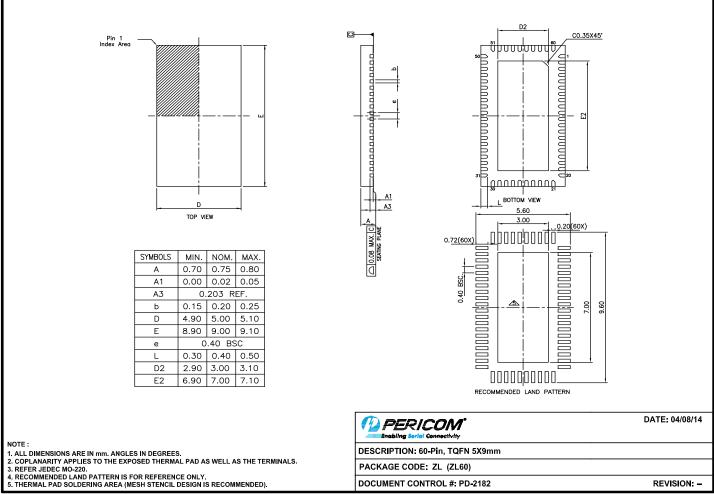
			Bit	Bit	Bit	Bit	Bit	Bit	Bit		Sta	tus
Phase	I ² C Transaction	Transmitting	7	6	5	4	3	2	1	R/W#	Master	Slave
1	Start	Master									Optional	-
2	Write command	Master	1	0	0	0	0	0	0	0	Optional	-
3	Acknowledge	Slave			-	Mandatory						
4	Word address offset Master				Word	addres	Optional	-				
5	Acknowledge	Slave						-	Mandatory			
6	Stop	Master	1					Optional	-			
7	Start	Master					Mandatory	-				
8	Read command	Master	1	0	0	0	0	0	0	1	Mandatory	-
9	Acknowledge	Slave									-	Mandatory
10	Read data	Slave	Data byte at Offset 0							-	Mandatory	
11	Acknowledge	Master					Mandatory					
12	Read data	Slave			Γ	Data by	-	Mandatory				
13											-	
											-	
40	Read data	Slave	Data byte at Offset 15								-	Mandatory
41	Not acknowlegde	Master									Mandatory	-
42	Stop	Master									Mandatory	-

Note: if the Slave does not acknowledge during the above transaction sequence, the entire sequence should be retried by the source.





Packaging Mechanical: ZL60



14-0044

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Ordering Information

Ordering Code	Package Code	Package Description					
PI3WVR31313AZLE	ZL	60-Pin, (TQFN) 5X9mm					
PI3WVR31313AZLEX	ZL	60-Pin, (TQFN) 5X9mm, Tape & Reel					

Notes:

· Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/

E = Pb-free and Green •

• Adding an X suffix = Tape/Reel





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